NSN 5962-01-253-0193

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delay time, high to low level

etc.).

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Body Lengtl	1:
1.290 inches	
Body Width:	
Between 0.5	00 inches and 0.610 inches
Body Height	
0.150 inches	
Maximum Po	ower Dissipation Rating:
1.02 watts	
Operating T	empurature Range:
-55.0/+125.0	degrees celsius
Storage Ten	npurature Range:
-65.0/+150.0	degrees celsius
End Applica	tion:
Radar set an	/sps-4 (v) 5
Features Pro	ovided:
Programmab	le and hermetically sealed and monolithic and bipolar and 3-state output and high impedance
Inclosure Ma	aterial:
Ceramic and	glass
Inclosure Co	onfiguration:
Dual-in-line	
Output Logi	c Form:
Transistor-tra	ansistor logic
Input Circuit	Pattern:
14 input	
Case Outline	e Source And Designator:
D-3 mil-m-38	510
Terminal Su	rface Treatment:
Solder	
Voltage Rati	ng And Type Per Characteristic:
7.0 volts pov	ver source
Time Rating	Per Chacteristic:
100.00 nano:	seconds propagation delay time, low to high level output and 100.00 nanoseconds propagation
output	
Memory Dev	vice Type:
Rom	
Test Data Do	ocument:
96906-mil-sto	d-883 standard (includes industry or association standards, individual manufactureer standards,
	pe And Quantity:
24 printed cir	
Shelf Life:	
N/a	

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

